



BSS138WQ

50V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
50V	3.5Ω @ Vgs = 10V	0.28A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor Control
- Power Management Functions

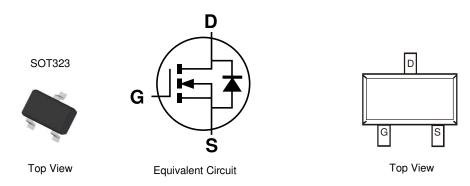
Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BSS138WQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)



Ordering Information (Note 4)

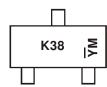
Part Number	Case	Packaging
BSS138WQ-7-F	SOT323	3,000/Tape & Reel
BSS138WQ-13-F	SOT323	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



K38 = Product Type Marking Code YM = Date Code Marking \overline{Y} = Year (ex: I = 2021)

M = Month (ex: 9 = September)

Date Code Key

2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
I	J	K	L	М	N	0	Р	R	S	Т	U
Jan	Feb	Mar	Apr	May	.lun	.lul	Aua	Sep	Oct	Nov	Dec
J	0	0	4	- may	oun	7	0	0	0	-	
	Jan	Jan Feb	I J K Jan Feb Mar	I J K L Jan Feb Mar Apr							



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		VDSS	50	V	
Gate-Source Voltage		V _{GSS}	±20	V	
ontinuous Drain Current (Note 6) $V_{GS} = 10V$ State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		ID	0.28 0.22	A	
Maximum Body Diode Continuous Current			ls	0.28	A
Pulsed Drain Current (10µs Pulse, Duty Cycle	= 1%)		ldм	1	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

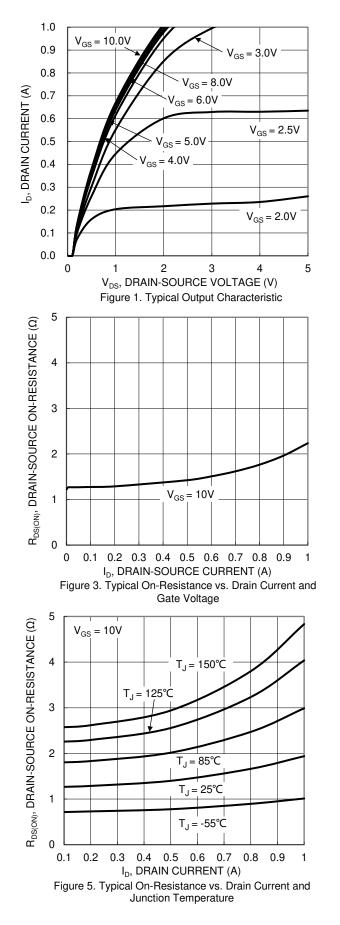
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	0.4	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	279	°C/W
Total Power Dissipation (Note 6)	PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	226	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

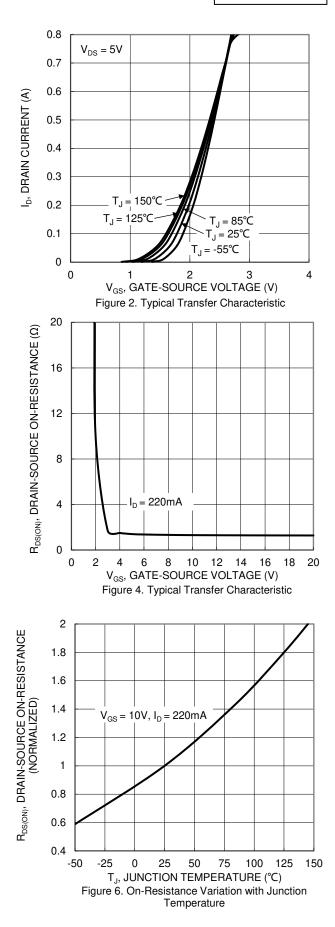
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV _{DSS}	50			V	$V_{GS} = 0V, I_D = 250 \mu A$		
Zero Gate Voltage Drain Current	IDSS			1	μA	$V_{DS} = 50V, V_{GS} = 0V$		
Gate-Body Leakage	IGSS	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage	VGS(TH)	0.5		1.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$		
Static Drain-Source On-Resistance	R _{DS(ON)}	_	1.2	3.5	Ω	$V_{GS} = 10V, I_D = 0.22A$		
Diode Forward Voltage	Vsd		0.8	1.2	٧	$V_{GS} = 0V, I_{S} = 0.2A$		
DYNAMIC CHARACTERISTICS (Note 8)								
Input Capacitance	Ciss	_	48	—	pF			
Output Capacitance	Coss	_	10	—	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz		
Reverse Transfer Capacitance	Crss	_	6	_	pF			
Gate Resistance	Rg	_	37.5	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$		
Total Gate Charge	Qg	_	1.5		nC			
Gate-Source Charge	Qgs	_	0.2	_	nC	V _{GS} = 10V ,V _{DS} = 25V, I _D = 0.2A		
Gate-Drain Charge	Qgd	_	0.3	_	nC			
SWITCHING CHARACTERISTICS (Note 8)								
Turn-On Delay Time	td(on)	_	3	—	ns			
Turn-On Rise Time	t _R		9		ns	$V_{DD} = 30V, I_D = 0.2A,$		
Turn-Off Delay Time	td(off)	_	43		ns	$V_{GS} = 10V, R_g = 150\Omega$		
Turn-Off Fall Time	tF	-	14		ns			
Reverse Recovery Time	trr		17.6		ns	1= 0.24 di/dt 1004/up		
Reverse Recovery Charge	QRR		9.5	—	nC	I⊧ = 0.2A, di/dt = 100A/μs		

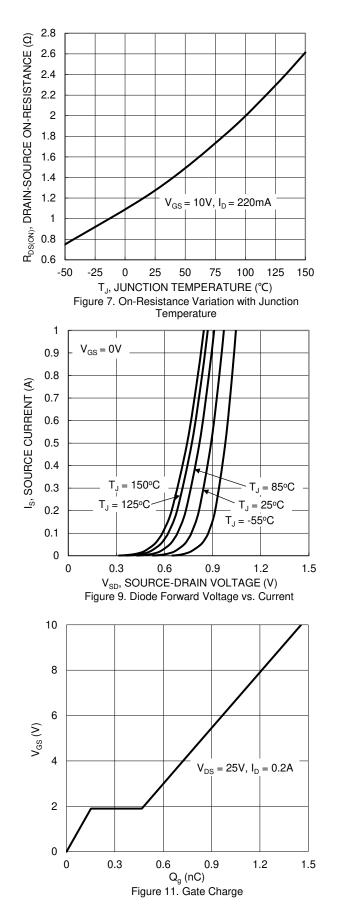
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:

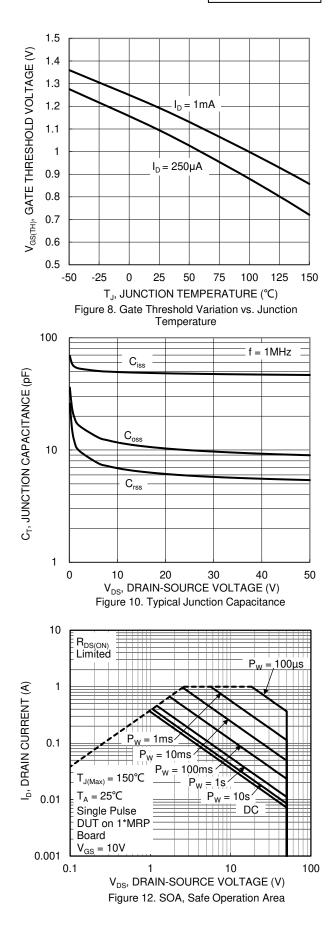






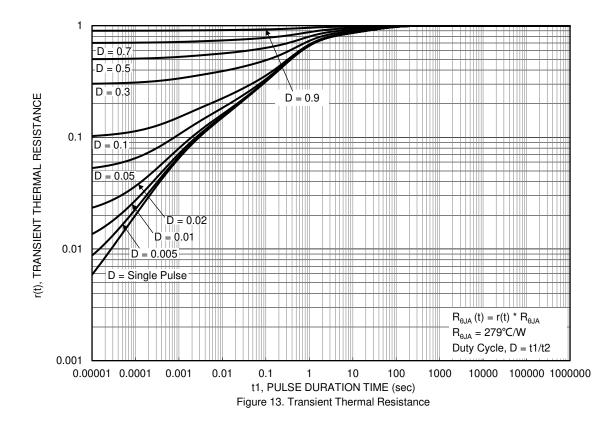






BSS138WQ Document number: DS42925 Rev. 2 - 2



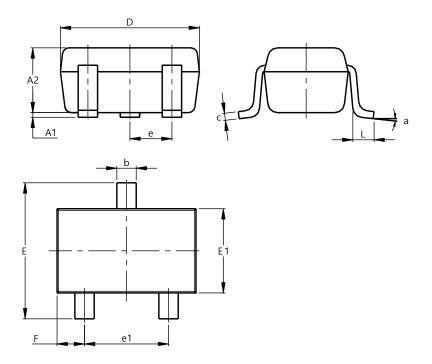




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

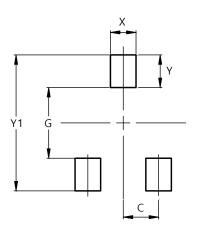
SOT323



SOT323							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.25	0.40	0.30				
С	0.10	0.18	0.11				
D	1.80	2.20	2.15				
ш	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	0.650 BSC						
e1	1.20	1.40	1.30				
F	0.375	0.475	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323

Dimensions	Value (in mm)
С	0.650
G	1.300
X	0.470
Y	0.600
Y1	2.500



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